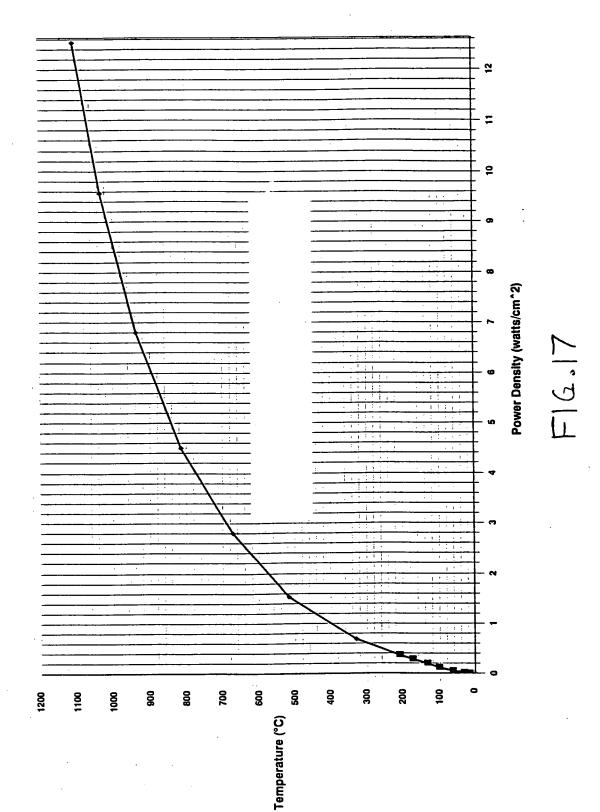
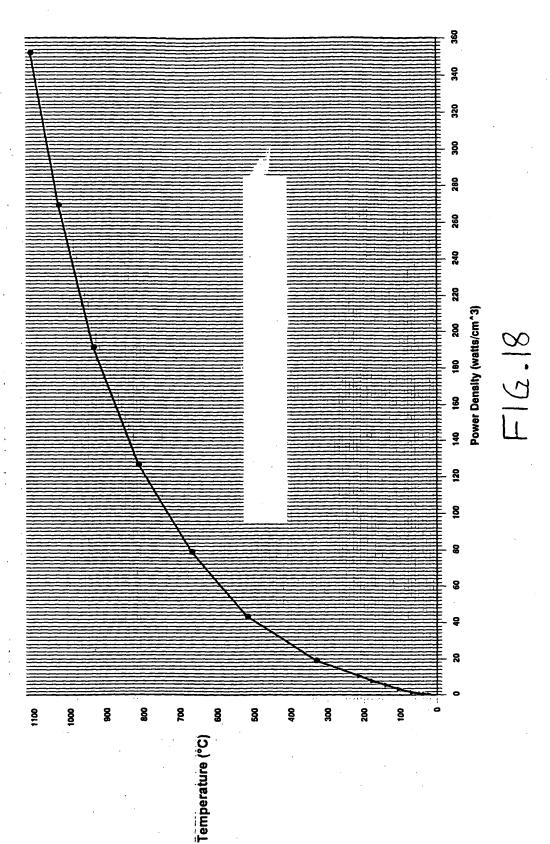
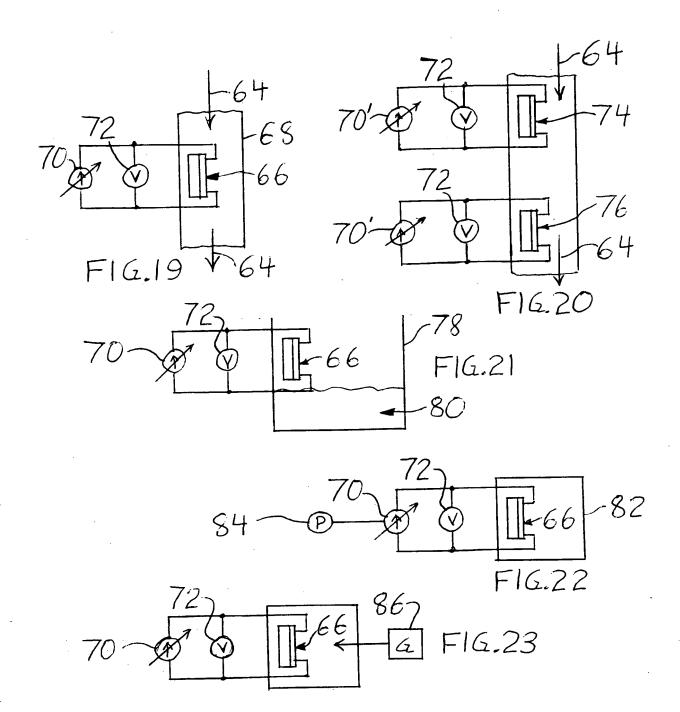


Resistivity (ohm-cm)







TEMPERATURE RANGE (°C) FOR DIFFERENT OPERATING ENVIRONMENTS

<b>→</b>	Air/Oxvgen	Ar, He or N <sub>2</sub>	H <sub>2</sub>	Vacuum
# 19.14	0.7	0001	1800 × 1800	<-196 to ~1800
<b>F</b>	<-196 to ~260	<-196 TO ~1800	202 02 02 - 3	
	106 +0 ~1250	<-196 to ~1800	<-196 to ~1800	<-196 to ~1800
2	221 22 251-2		-	196 +0 ~1000
. ~	<-196 to ~1000	<-196 to ~1000	<-196 to ~1000	222 22 261-2
ר				/-20 to ~1300
<b>V</b>	<-20 to ~1250	$< -20$ to $\sim 1300$	Not Applicable	0000
ť			7	1300
Ľ	7-20 to ~1250	<-20 to ~1300	<-20 to ~1300	<
n	)		. 1	
	/-196 to ~1250	<-196 to ~1300	Not Applicable	Not Applicable
٥	000			106 ±0 ~1300
α	<-196 to ~1250	<-196 to ~1300	<-196 to ~1300	005T 00 86T->
0				196 +0 ~1300
C	/-196 to ~1250	<-196 to ~1300	<-196 to ~1300	20CT 01 86T->
7				0001~ 04 301
, r	7-196 ±0 ~1250	<-196 to ~1400	<-196 to ~1400	- 130 CO T-300
OT	1			

FIG. 24

## TEMPERATURE SENSORS

C	Best Completed Structure	tructure	Platinum Thin-Film	Thermistor
רוומדמרכבידפרים	FIG. #	Result	RTD	
Max. Zero-Drift Temperature (°C) · Steady State · Thermal Cycling	1,2,4,5,6,8,9,10	>1200 >1200	~500 ~400	0 >
Internal Drift Mechanisms (Within Zero-Drift Temp. Range) Grain-Growth Densification: Diffusion (Measureable):	1,2,4,5,6,8,9,10 1,2,4,5,6,8,9,10 1,2,4,5,6,8,9,10	N O ON ON	0 0 0 0 0	Yes Yes Yes
<ul> <li>Expanison Mismatch (α)</li> <li>Substrate/Circuit</li> <li>Electrode/Circuit</li> </ul>	1	\$0.06 ~0	~0.13 ~0	0 >0.3
Maximum Temperature (°C) vs Environments · Unencapsulated:	2,4,5,6,8,9,10 1,2 1,2	~1250 ~1800 ~1800	~850 ~850 Not Applicable	~ 300 ~ 300 ~ 300
• Vacuum • Encapsulated • Oxygen • Ar, He, Nz	1,2 1,2,10 1,2,10 1,2,10	~1800 ~1400 ~1400 ~1400	NOC APPLICALIE ~850	~300 ~300 ~300
Precision Limit: (°C)	1,2	±0.0001	±0.001	10.01
Resp nse Time (Ratio to Platium Thin-Film RTD)	1,2,4,5,6,8,9,10	50.1	1	22
Resp nse Type:	1,2,4,5,6,8,9,10	~Linear	~Linear	Exponential
Substrat Thermal Conductivity (W/cm/°K)	1-6,8-10	2.4	0.35	50.1
Maximum Temperature Range (°C)	1,2	<-195 to ~1800	<-195 to ~850	<0 to ~800

## HEATER STRUCTURES

Characteristics	oleted Struct	ures Droperty	Bulk	Foil	Rods & Bars	Planar Heaters	Wire
	FIG. #	To and a			94	Plane	Line
Source Type	1-6,8-10	Plane	Plane	Plane	DTILLE		
Heating Modes				Č.	No	Yes	No
. Contact	1-6,8-10	res	163			Vea	Yes
. Radiative	1-6,8-10	Yes	Yes	Yes	ממ		000
ΔT(°C)Heater-Object	1-6,8-10	~100	~100	~100	~800	~100	00614
@2" (5cm)							
Max.Temp.(°C) vs							
Environment			~1300	~1000	~1000	~700	~300
. Oxygen	3 (capped)	~TROO				000	~3000
IN CLASS OF THE CONTRACT OF TH	1,2	~1800	~1300	~3000	~3000	00/2	
Ar, he, w <sub>2</sub>		000	~1300	~3000	~3000	~ 700	~3000
. Vacuum	1,2	0001				700	~1800
. Hydrogen	1,2	~1800	~1300	~3000	0005~	007	
Time to Max. Temp.	1,2,4,5,6,8,9,10			·			
(°C), (Seconds)		,	760	<30	<60	. 09>	<3
. Heater	1,2,4,5,6,8,9,10	2			000	067	<10
· Object@2"(5cm)	1,2,4,5,6,8,9,10	44	· e0	<120	0772		
Radiative Heating	1,2,4,5,6,8,9,10	Excellent	Very Good	Very Good	Poor	Excellent	Poor
Efficiency					4/N	0.26-2.4	N/A
Substrate Thermal	1-6,8-10	2.4	2.4	1.0∼			
Conducting (W/cm/'K)					ı		

FIG. 26